

SKY77768 Power Amplifier Module for WCDMA / HSDPA / HSUPA / HSPA+ / LTE – Band VIII (880 MHz–915 MHz)

Applications

- WCDMA handsets
- HSDPA
- HSUPA
- HSPA+
- LTE

Features

- Low voltage positive bias supply 3.2 V to 4.2 V
- Good linearity
- High efficiency
 - 50% at 28.5 dBm
- Large dynamic range
- Small, low profile package
 - 3 mm x 3 mm x 0.9 mm
 - 10-pad configuration
- Power down control
- InGaP
- Supports low collector voltage operation
- Digital Enable
- No V_{REF} required
- CMOS compatible control signals
- Integrated Directional Coupler

Description

The SKY77768 Power Amplifier Module (PAM) is a fully matched 10-pad surface mount module developed for Wideband Code Division Multiple Access (WCDMA) applications. This small and efficient module packs full 880-915 MHz bandwidth coverage into a single compact package. Because of high efficiencies attained throughout the entire power range, the SKY77768 delivers unsurpassed talk-time advantages. The SKY77768 meets the stringent spectral linearity requirements of High Speed Downlink Packet Access (HSDPA), High Speed Uplink Packet Access (HSUPA), and Long Term Evolution (LTE) data transmission with high power added efficiency. An integrated directional coupler eliminates the need for any external coupler.

The Gallium Arsenide (GaAs) Microwave Monolithic Integrated Circuit (MMIC) contains all amplifier active circuitry, including input and interstage matching circuits. The silicon CMOS support die, providing precision biasing for the MMIC affords a true CMOS-compatible control interface. Output match into a 50-ohm load, realized off-chip within the module package, optimizes efficiency and power performance.

The SKY77768 is manufactured with Skyworks' InGaP GaAs Heterojunction Bipolar Transistor (HBT) process which provides for all positive voltage DC supply operation and maintains high efficiency and good linearity. While primary bias to the SKY77768 can be supplied directly from any suitable battery with an output of 3.2 V to 4.2 V, optimal performance is obtained with VCC2 sourced from a DCDC power supply adjusted within 0.5 V to 3.6 V based on target output power levels. Power down executes by setting VENABLE to zero volts. No external supply side switch is needed as typical "off" leakage is a few microamperes with full primary voltage supplied from the battery.

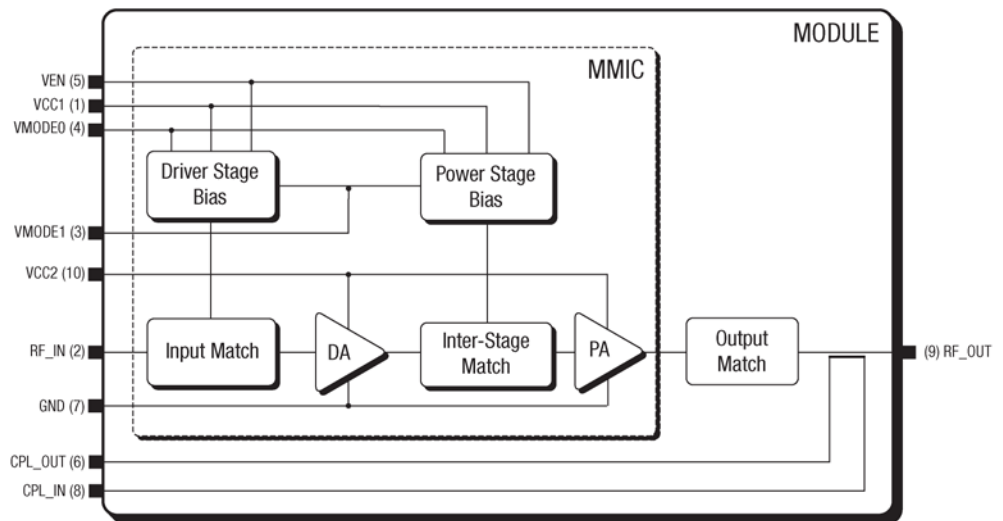
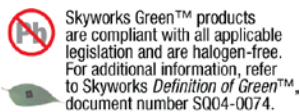


FIGURE 1. SKY77768 FUNCTIONAL BLOCK DIAGRAM

Electrical Specifications

The following tables list the electrical characteristics of the SKY77768 Power Amplifier. Table 1 lists the absolute maximum ratings and Table 2 shows the recommended operating conditions. Electrical specifications for nominal operating

conditions are listed in Table 4. Table 3 presents a truth table for the power settings. Tables 5 through 8 provide the standard test configurations for WCDMA (STC1), HSDPA (STC2), and HSUPA (STC3, STC4) respectively.

TABLE 1. ABSOLUTE MAXIMUM OPERATING CONDITIONS

No damage assuming only one parameter set at limit at a time with all other parameters set at nominal value.

Parameter	Symbol	Minimum	Nominal	Maximum	Unit	
RF Input Power	P _{IN}	—	0	10	dBm	
Supply Voltage ¹	No RF	V _{CC1}	—	3.8	6.0	Volts
		With RF	—	3.8	5.0	
	No RF	V _{CC2}	—	3.4	6.0	
		With RF	—	3.4	4.6	
Enable Control Voltage	V _{EN}	—	1.8	4.2	Volts	
Mode Control Voltage	V _{MODE0}	—	1.8	4.2	Volts	
	V _{MODE1}	—	1.8	4.2		
Case Temperature ²	Operating	T _{CASE}	–30	+25	+110	°C
	Storage	T _{STG}	–40	—	+150	

¹ Overvoltage shutdown circuitry turns on at approximately 5 V.

² Case Operating Temperature (TCASE) refers to the temperature of the GROUND PAD at the underside of the package.

TABLE 2. RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Minimum	Nominal	Maximum	Unit	
RF Output Power ¹	WCDMA	P _{OUT_MAX}	28.50	—	—	dBm
	HSDPA		27.50	—	—	
	HSUPA		24.85	—	—	
	LTE		27.50	—	—	
Operating Frequency	f ₀	880.0	897.5	915.0	MHz	
Supply Voltage	V _{CC1}	3.0 ²	3.4	4.5	Volts	
	V _{CC2}	0.5	—	3.6		
Enable Control Voltage	Low	V _{EN_L}	0.0	0.0	0.5	Volts
	High	V _{EN_H}	1.35	1.8	3.1	
Mode Control Voltage	Low	V _{MODE0}	0.0	0.0	0.5	Volts
		V _{MODE1}	0.0	0.0	0.5	
	High	V _{MODE0}	1.35	1.8	3.1	
		V _{MODE1}	1.35	1.8	3.1	
Case Operating Temperature ³	T _{CASE}	–20	+25	+85	°C	

¹ For VCC < 3.4 V, output power back-off = 0.5 dB.

² Recommended minimum VCC for maximum power output is indicated. Vcc2 down to 0.5 V may be used for backed-off power when using DC/DC converter to conserve battery current.

³ Equivalent to –30 °C to +75 °C Ambient Operating Temperature

TABLE 3. MODES OF OPERATION

Power Setting	ENABLE	VMODE0	VMODE1	VCC
Power Down Mode	Low	Low	Low	On
Standby Mode	Low	—	—	On
High Power Mode (17.0 dBm ≤ P _{OUT} ≤ 28.5 dBm)	High	Low	—	On
Medium Power Mode (7.0 dBm ≤ P _{OUT} ≤ 17.0 dBm)	High	High	Low	On
Low Power Mode (P _{OUT} ≤ 7.0 dBm)	High	High	High	On

TABLE 4. ELECTRICAL SPECIFICATIONS FOR NOMINAL OPERATING CONDITIONS

Per Table 2 over dynamic range up to 28.5 dBm output power for STC1 modulation, unless otherwise specified.

Characteristics	Symbol	Condition	Minimum	Typical	Maximum	Unit	
Gain ¹	GLOW	P _{OUT} = 7.0 dBm V _{CC2} = 0.8 V	10.0	14.0	21.5	dB	
	GMED	P _{OUT} = 17.0 dBm V _{CC2} = 1.5 V	19.0	24.0	28.0		
	GHIGH	P _{OUT} = 28.5 dBm	25.0	28.0	31.0		
Rx Band Gain	RxG	—	—	—	-0.5	dB	
	RxG_GPS	—	—	—	-3.0		
	RxG_JSM	—	—	—	-6.0		
Power Added Efficiency	PAE _{LOW}	P _{OUT} = 7.0 dBm	10.5	13.0	—	%	
	PAE _{MED}	P _{OUT} = 17.0 dBm	22.0	26.5	—		
	PAE _{HIGH}	P _{OUT} = 28.5 dBm	43.0	50.0	—		
Total Supply Current	I _{CC_LOW}	P _{OUT} = 7.0 dBm	—	44	55	mA	
	I _{CC_MED}	P _{OUT} = 17.0 dBm	—	122	150		
	I _{CC_HIGH}	P _{OUT} = 28.5 dBm	—	420	500		
Quiescent Current	I _{Q_LOW}	Low Power Mode	—	22	28	mA	
	I _{Q_MED}	Medium Power Mode	—	38	45		
Enable Control Current	I _{EN}	—	—	20	40	μA	
Mode Control Current	I _{MODE0}	—	—	20	40	μA	
	I _{MODE1}	—	—	20	40		
Total Supply Current in Power Down Mode	I _{PD}	V _{CC} = 3.4 V V _{EN} = Low V _{MODE0} = Low V _{MODE1} = Low	—	—	20	μA	
ICC1 Current	I _{CC1_HIGH}	—	—	—	10	mA	
Adjacent Channel Leakage power Ratio ²	5 MHz offset	ACLR5	P _{OUT} = 7.0 dBm	—	-43	-40.0	dBc
			P _{OUT} = 17.0 dBm	—	-45	-40.0	
			P _{OUT} = 28.5 dBm	—	-41	-38.5	
	10 MHz offset	ACLR10	P _{OUT} = 7.0 dBm	—	-59	-50.0	
			P _{OUT} = 17.0 dBm	—	-56	-50.0	
			P _{OUT} = 28.5 dBm	—	-58	-50.0	

TABLE 4. [CONTINUED] ELECTRICAL SPECIFICATIONS FOR NOMINAL OPERATING CONDITIONS
Per Table 2 over dynamic range up to 28.5 dBm output power for STC1 modulation, unless otherwise specified.

Characteristics	Symbol	Condition	Minimum	Typical	Maximum	Unit	
Adjacent Channel Leakage power Ratio ³	EUTRA offset	ACLR_EUTRA	$P_{OUT} \leq (P_{OUT_MAX} - MPR^4)$	—	-40	—	dBc
	UTRA offset	ACLR1_UTRA	—	—	-42	—	
		ACLR2_UTRA	—	—	—	—	
Harmonic Suppression	Second	fo2	$P_{OUT} \leq 28.5$ dBm	—	-45	-35	dBc
	Third	fo3		—	-50	-45	
Tx Noise in Rx Bands ¹	Rx Band 1		925 MHz–960 MHz	—	-136	-134	dBm/Hz
	GPS Rx		1574 MHz–1577 MHz	—	—	-140	
	ISM Rx		2400 MHz–2483.5 MHz	—	—	-143	
EVM		EVM1	$P_{OUT} = P_{OUT_MAX}$	—	—	3.35	%
		EVM2	$P_{OUT} = P_{OUT_MAX} - 3$	—	—	2.50	
Rise / Fall Time	DC	TON_DC	—	—	—	20	μ s
		TOFF_DC	—	—	—	20	
	RF	TON_RF	—	—	—	6	
		TOFF_RF	—	—	—	6	
Coupling Factor	CPL	$P_{OUT} = P_{OUT_MAX}$	-22	-20	-18	dB	
CPL_OUT / P _{OUT} Power Ratio Variation Over Output VSWR			2.5:1 VSWR at P _{OUT} all VSWR phases CPL_IN 50 Ω terminated	—	± 0.4	—	dB
Daisy-chain	VSWR		CPL_IN and CPL_OUT ports 698 MHz to 2620 MHz VEN = Low	—	—	1.3:1	
	Insertion Loss		CPL_IN to CPL_OUT ports 698 MHz to 2620 MHz VEN = Low	—	—	0.45	dB
Input Voltage Standing Wave Ratio	VSWR		—	—	1.2:1	1.9:1	—
Stability (Spurious output) ¹	S		6:1 VSWR All phases	—	—	-70	dBc
Ruggedness – no damage ^{1,5}	Ru		$P_{OUT} \leq 28.5$ dBm	10:1	—	—	VSWR

¹ Over conditions

² ACLR is expressed as a ratio of total adjacent power to WCDMA modulated in-band, both measured in 3.84 MHz bandwidth at specified offsets.

³ LTE: EVM and ACLR are measured with QPSK modulation with 1.4 MHz bandwidth and 5 resource blocks. (Maximum Power Reduction = 0 dBm per 3GPP TS36.101.

⁴ MPR is the maximum power reduction as defined in 3GPP TS36.101

⁵ All phases, time = 10 seconds.

TABLE 5. STANDARD TEST CONFIGURATION – STC1 WCDMA MODE

Parameter	Level	Spread Code	Spread Factor	I/Q	β_c	β_d	β_{hs}	β_{ec}	β_{ed}	Relative Power (dB)
DPCCH	15 kbps	0	256	Q	8/15	—	—	—	—	-6.547
DPDCH	60 kbps	16	64	I	—	15/15	—	—	—	-1.087

TABLE 6. STANDARD TEST CONFIGURATION – STC2 HSDPA MODE

Parameter	Level	Spread Code	Spread Factor	I/Q	β_c	β_d	β_{hs}	β_{ec}	β_{ed}	Relative Power (dB)
DPCCH	15 kbps	0	256	Q	12/15	—	—	—	—	-7.095
DPDCH	60 kbps	16	64	I	—	15/15	—	—	—	-5.157
HS-DPCCH	15 kbps	64	256	Q	—	—	24/15	—	—	-3.012

TABLE 7. STANDARD TEST CONFIGURATION – STC3 HSUPA MODE

Parameter	Level	Spread Code	Spread Factor	I/Q	β_c	β_d	β_{hs}	β_{ec}	β_{ed}	Relative Power (dB)
DPCCH	15 kbps	0	256	Q	8/15	—	—	—	—	-19.391
DPDCH	960 kbps	1	4	I	—	15/15	—	—	—	-13.931
HS- DPCCH	15 kbps	64	256	Q	—	—	8/15	—	—	-19.391
E-DPCCH	15 kbps	1	256	I	—	—	—	10/15	—	-17.338
E-DPDCH	960 kbps	2	4	I	—	—	—	—	71.5/15	-0.371

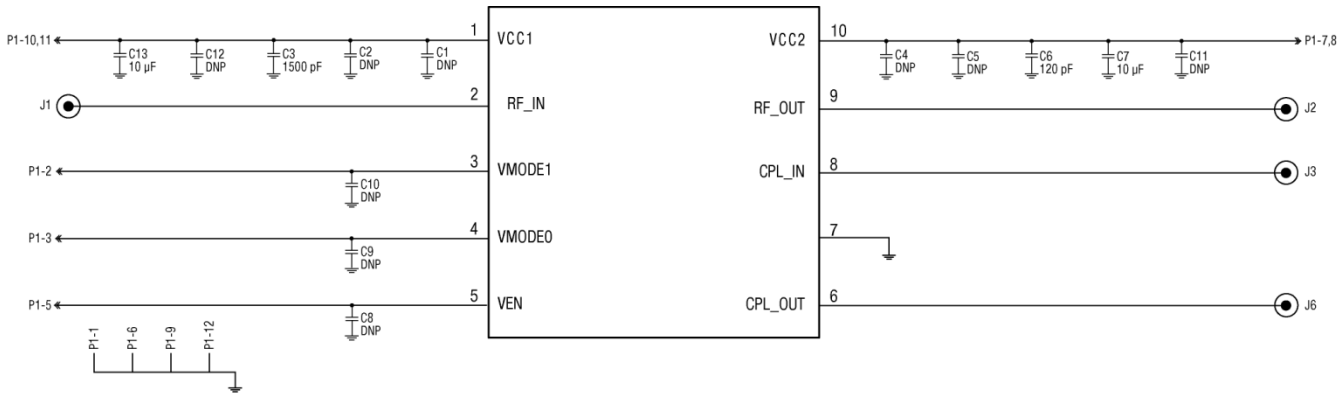
TABLE 8. STANDARD TEST CONFIGURATION – STC4 HSUPA MODE

Parameter	Level	Spread Code	Spread Factor	I/Q	β_c	β_d	β_{hs}	β_{ec}	β_{ed}	Relative Power (dB)
DPCCH	15 kbps	0	256	Q	6/15	—	—	—	—	-12.499
DPDCH	960 kbps	1	4	I	—	15/15	—	—	—	-4.540
HS- DPCCH	15 kbps	64	256	Q	—	—	2/15	—	—	-22.041
E-DPCCH	15 kbps	1	256	I	—	—	—	12/15	—	-6.478
E-DPDCH	960 kbps	2	4	I	—	—	—	—	15/15	-4.425

Evaluation Board Description

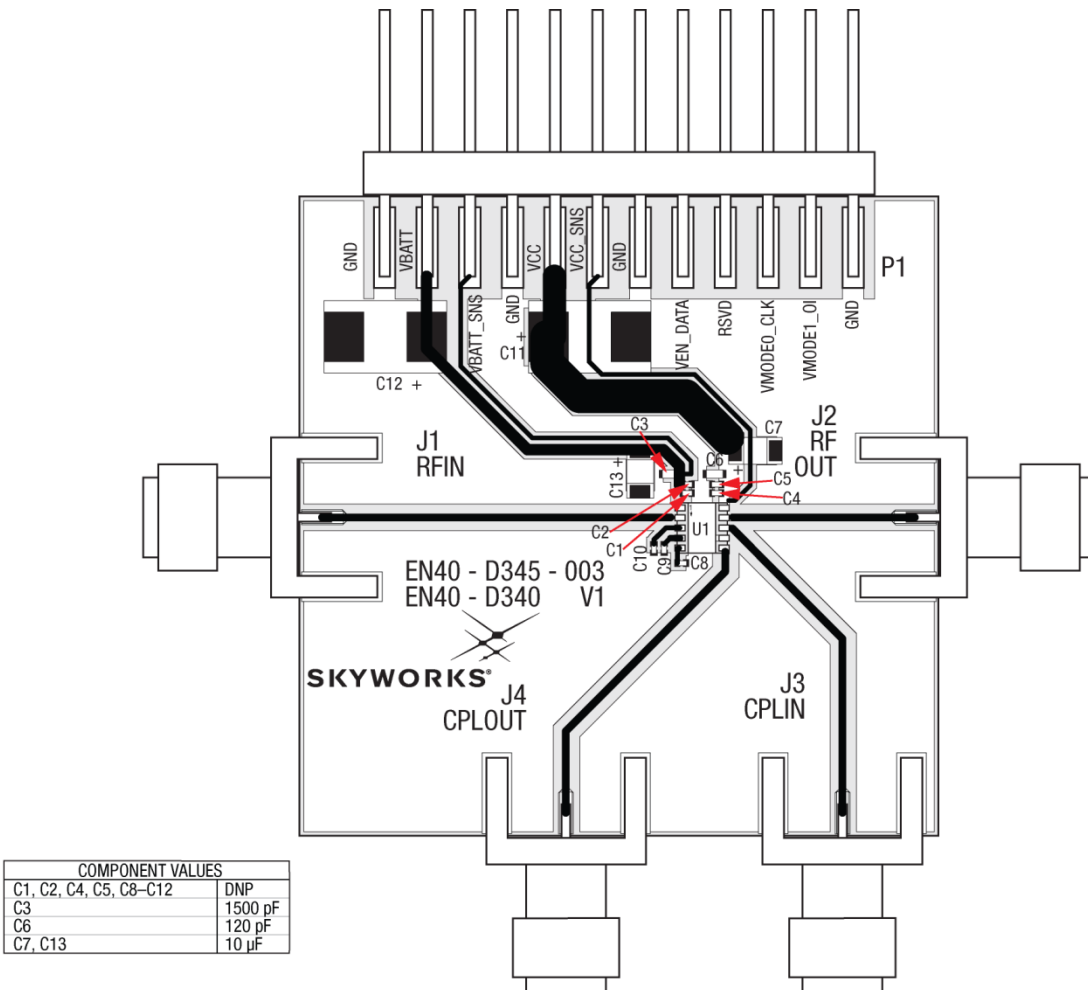
The evaluation board is a platform for testing and interfacing design circuitry. To accommodate the interface testing of the SKY77768, the evaluation board schematic and assembly

diagrams are included for preliminary analysis and design. Figure 2 shows the basic schematic of the board for the 880 MHz to 915 MHz range shown in Figure 3. Figure 4 is a schematic of the recommended application shown in Figure 5.



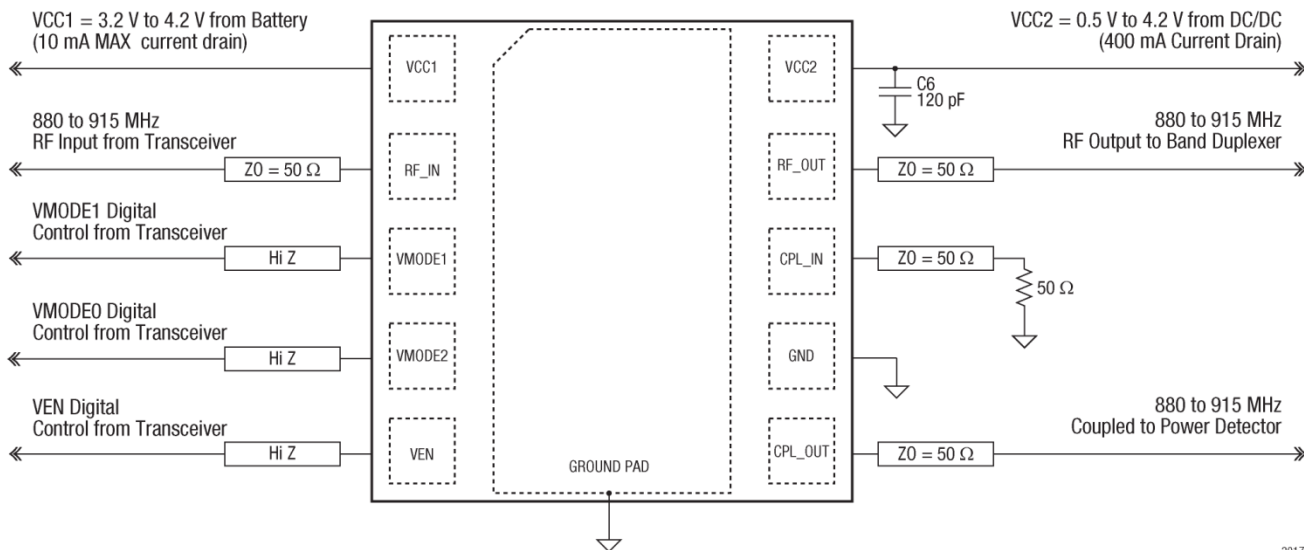
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FIGURE 2. EVALUATION BOARD SCHEMATIC



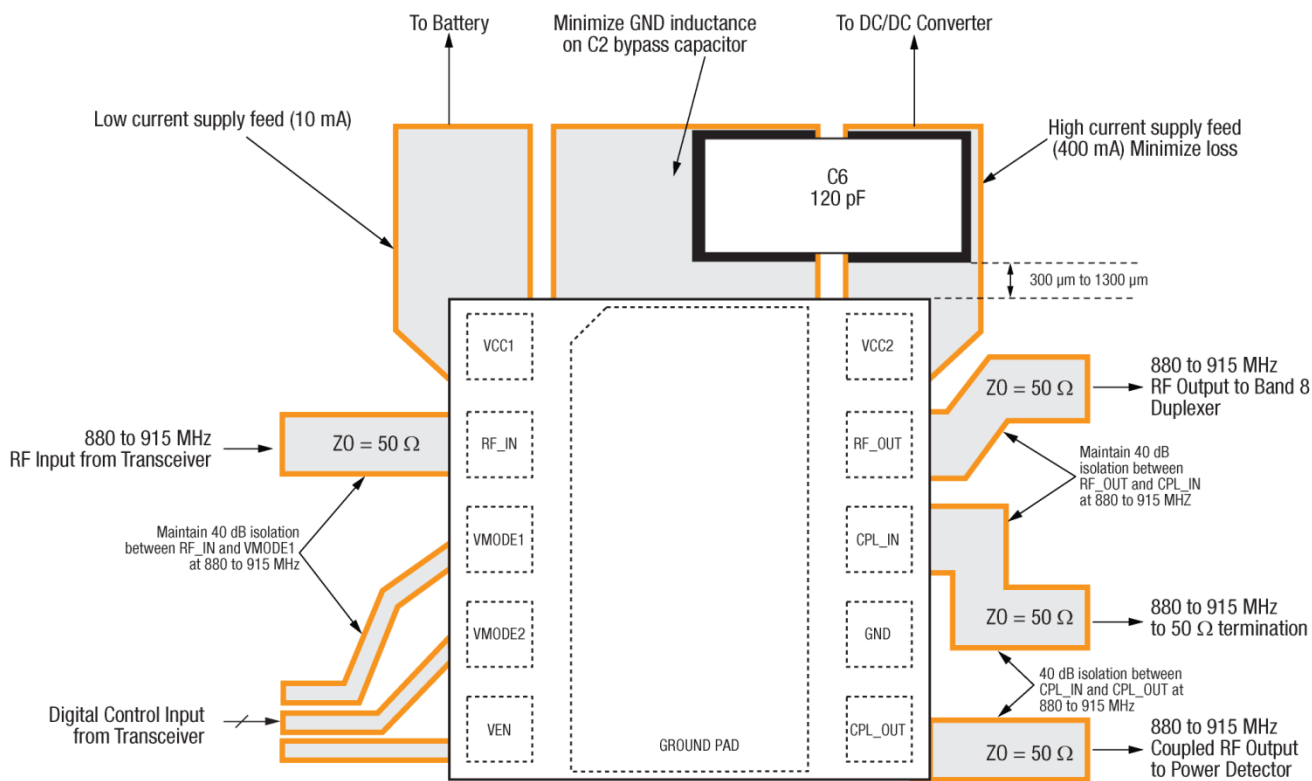
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FIGURE 3. EVALUATION BOARD ASSEMBLY DIAGRAM



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FIGURE 4. SKY77768 SCHEMATIC FOR RECOMMENDED APPLICATION DIAGRAM



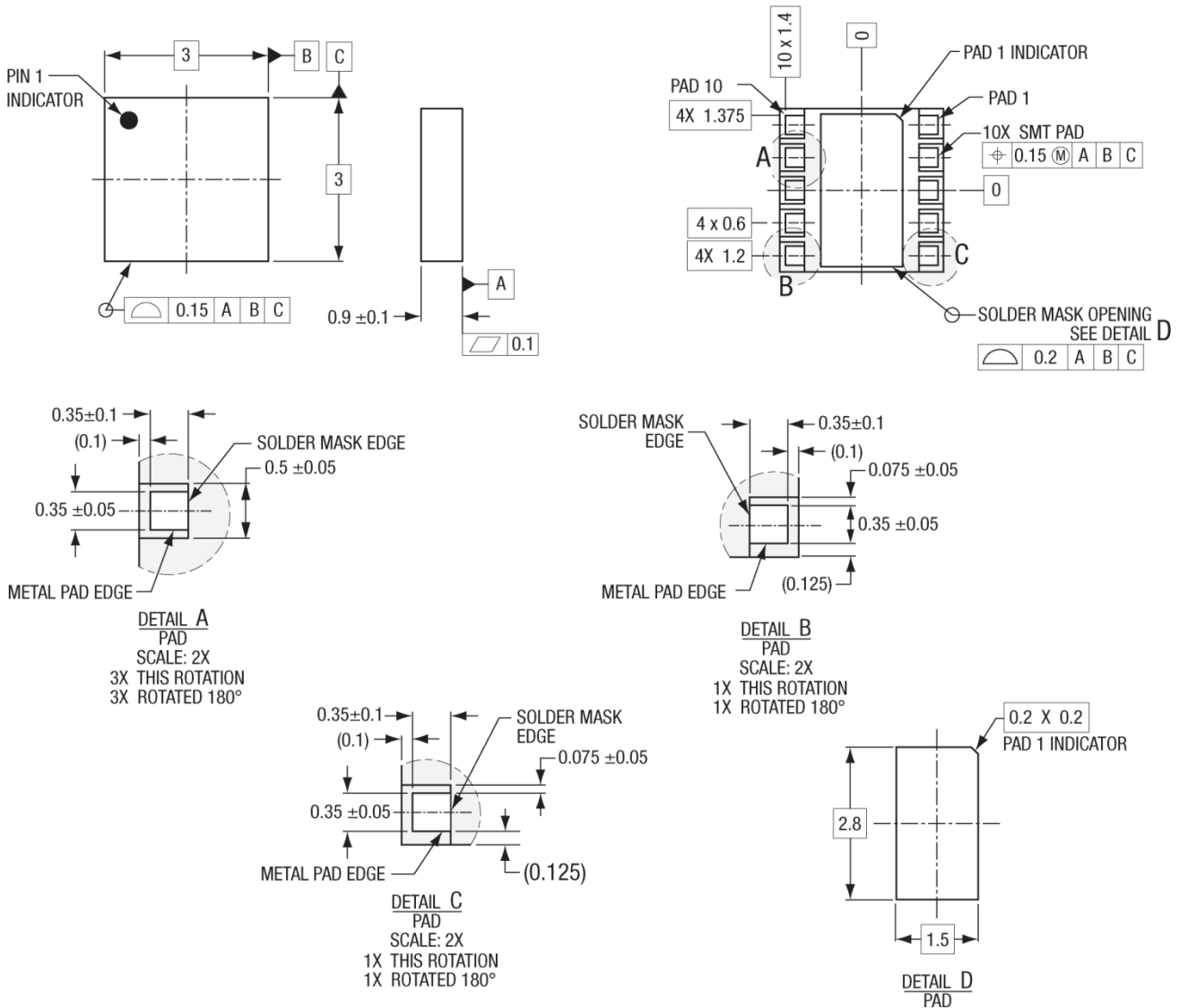
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FIGURE 5. SKY77768 RECOMMENDED APPLICATION DIAGRAM

Package Dimensions

The SKY77768 is a multi-layer laminate base, overmold encapsulated modular package designed for surface mount solder attachment to a printed circuit board. Figure 6 is a mechanical drawing of the pad layout for this package. Figure 7 provides a

recommended phone board layout footprint for the PAM to help the designer attain optimum thermal conductivity, good grounding, and minimum RF discontinuity for the 50-ohm terminals.



- NOTES: Unless otherwise specified.
 1. Dimensioning and Tolerancing in accordance with ASME Y14.5M-1994
 2. All dimensions are in millimeters.

DS_D804_77761 REV 1 2/08/12
201722_006

FIGURE 6. DIMENSIONAL DIAGRAM FOR 3 mm x 3 mm x 0.9 mm PACKAGE – SKY77768 SPECIFIC

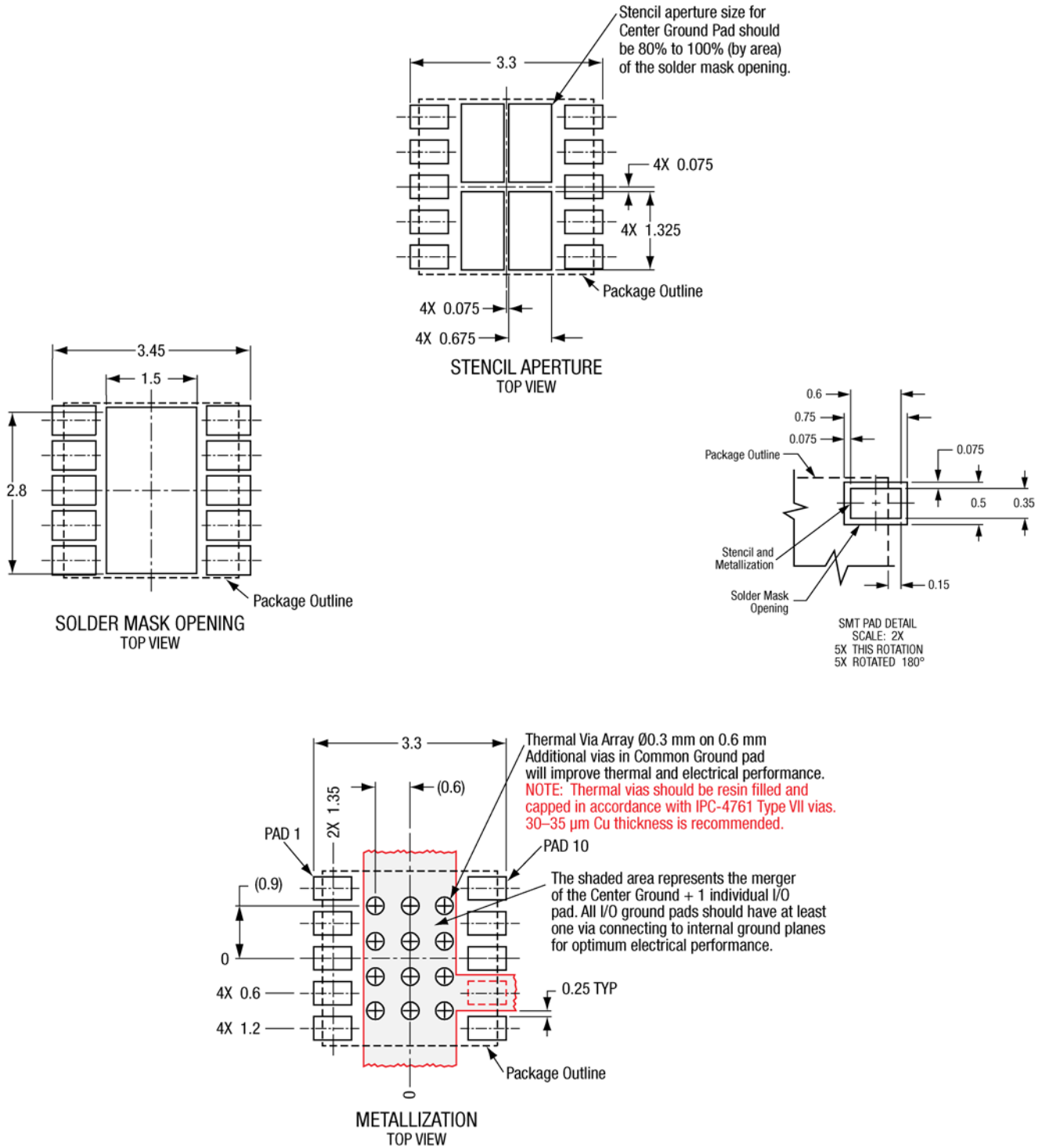
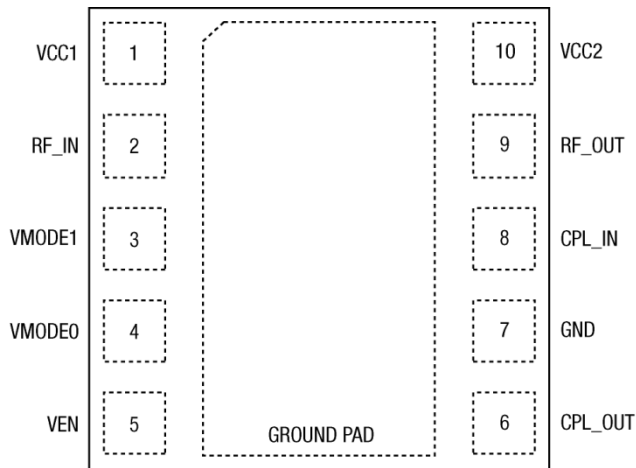


FIGURE 7. PHONE PCB LAYOUT DIAGRAM – 3 mm x 3 mm, 10-PAD PACKAGE – SKY77768

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Package Description

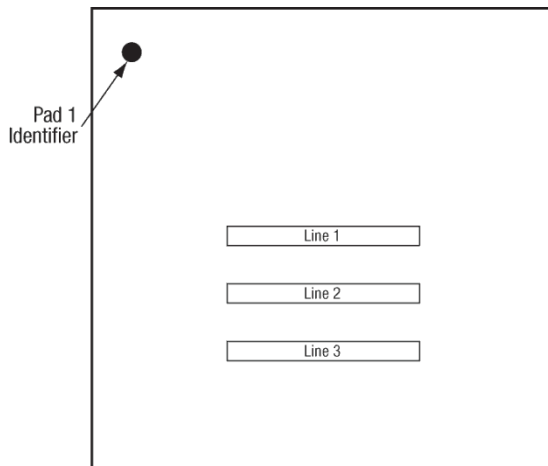
Figure 8 shows the pad functions and the pad numbering convention, which starts with pad 1 in the upper left and



Pad layout as seen from Top View looking through the package. GROUND PAD is package underside.

201722_006

FIGURE 8. SKY77768 PAD NAMES AND CONFIGURATION (TOP VIEW)



NOTE: Lines 1, 2, 3 have a maximum of 7 characters
 Line 1 = Part Number and Version
 Line 2 = Lot Number
 Line 3 = Year–Week–Country Code (MX)

201075_007

FIGURE 9. TYPICAL CASE MARKINGS

Package Handling Information

Because of its sensitivity to moisture absorption, this device package is baked and vacuum-packed prior to shipment. Instructions on the shipping container label must be followed regarding exposure to moisture after the container seal is broken, otherwise, problems related to moisture absorption may occur

increments counter-clockwise around the package. Typical case markings are illustrated in Figure 9.

when the part is subjected to high temperature during solder assembly.

The SKY77768 is capable of withstanding an MSL3/260 °C solder reflow. Care must be taken when attaching this product, whether it is done manually or in a production solder reflow environment. If the part is attached in a reflow oven, the temperature ramp rate should not exceed 3 °C per second; maximum temperature should not exceed 260 °C. If the part is manually attached, precaution should be taken to insure that the part is not subjected to temperatures exceeding 260 °C for more than 10 seconds. For details on attachment techniques, precautions, and handling procedures recommended by Skyworks, please refer to Skyworks Application Note: *PCB Design and SMT Assembly/Rework*, Document Number 101752. Additional information on standard SMT reflow profiles can also be found in the JEDEC Standard J-STD-020.

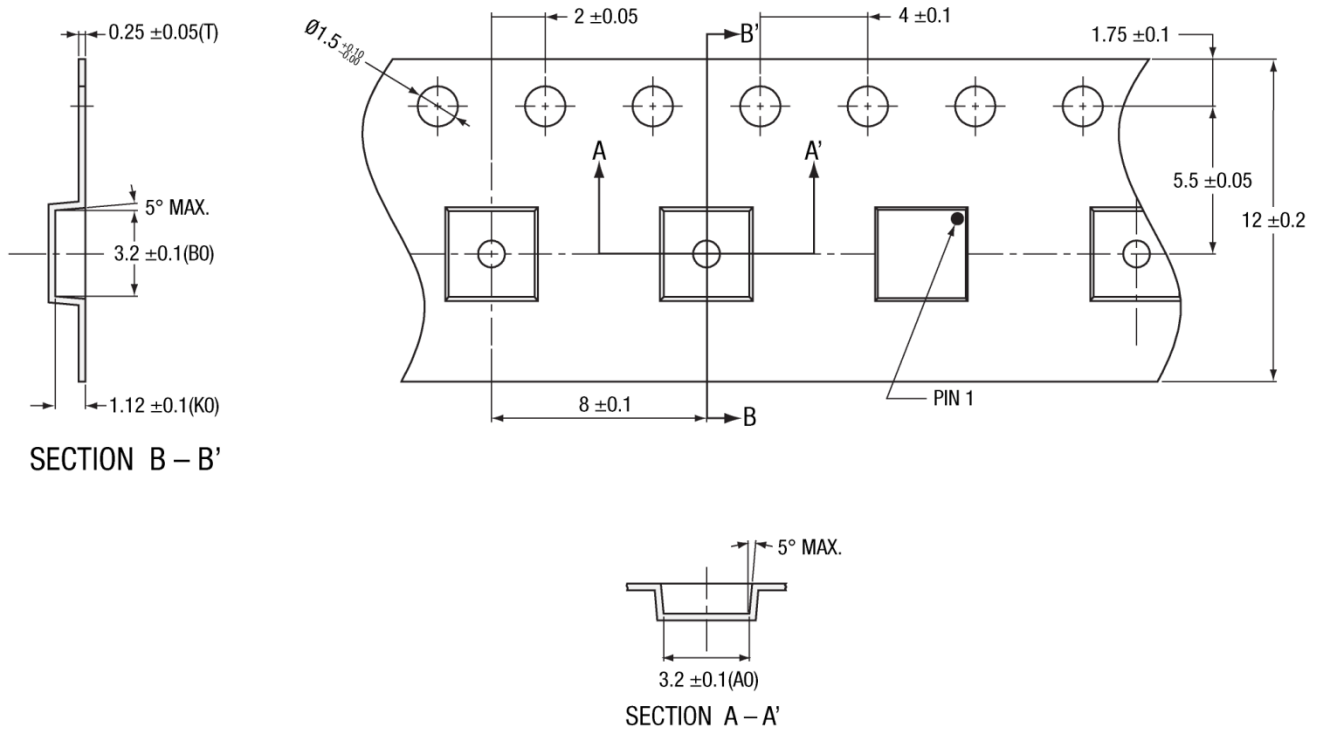
Production quantities of this product are shipped in the standard tape-and-reel format (Figure 10).

Electrostatic Discharge (ESD) Sensitivity

The SKY77768 meets class 1C JESD22-A114 Human Body Model (HBM), class IV JESD22-C101 Charged-Device Model (CDM), and class A JESD22-A115 Machine Model (MM) electrostatic discharge (ESD) sensitivity classification.

To avoid ESD damage, both latent and visible, it is very important that the product assembly and test areas follow the ESD handling precautions listed below.

- Personnel Grounding
 - Wrist Straps
 - Conductive Smocks, Gloves and Finger Cots
 - Antistatic ID Badges
- Protective Workstation
 - Dissipative Table Top
 - Protective Test Equipment (Properly Grounded)
 - Grounded Tip Soldering Irons
 - Solder Conductive Suckers
 - Static Sensors
- Facility
 - Relative Humidity Control and Air Ionizers
 - Dissipative Floors (less than 1,000 MΩ to GND)
- Protective Packaging and Transportation
 - Bags and Pouches (Faraday Shield)
 - Protective Tote Boxes (Conductive Static Shielding)
 - Protective Trays
 - Grounded Carts
 - Protective Work Order Holders



NOTES:

1. CARRIER TAPE IS BLACK CONDUCTIVE POLYCARBONATE OR POLYSTYRENE.
2. COVER TAPE IS TRANSPARENT AND CONDUCTIVE.
3. ESD-SURFACE RESISTIVITY IS $\leq 1 \times 10^{10}$ OHMS/SQUARE PER EIA, JEDEC TNR SPECIFICATION.
4. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE: ± 0.2 mm
5. A_0 & B_0 MEASURED ON PLANE 0.3 mm ABOVE THE BOTTOM OF THE POCKET.
6. ALL DIMENSIONS ARE IN MILLIMETERS.

CARRIER TAPE OVERMOLD MCM / RFLGA 3 x 3 x 0.75 / 0.90 mm BODY SIZE -108A
201075_008

FIGURE 10. DIMENSIONAL DIAGRAM FOR CARRIER TAPE BODY SIZE – 3 mm x 3 mm x 0.75 / 0.90 mm – MCM